

MINISTRY OF SUPPLY (S.R.D.E.)

(NR68/6Q7G/POVT194)

Specification MOS/CV587/Issue 6	<u>SECURITY</u>	
Dated:- 18.6.46	<u>Specification</u>	<u>Valve</u>
To be read in conjunction with K1001.	Restricted	Restricted

→ indicates a change

<u>TYPE OF VALVE:-</u> Double diode triode			<u>MARKING</u>		
<u>CATHODE:-</u> Indirectly heated			See K1001/4		
<u>ENVELOPE:-</u> Glass-unmetallised			Additional marking:-		
<u>PROTOTYPE:-</u> 6Q7G, DH63			6Q7G.		
<u>RATING</u>		Note	<u>BASE</u>		
			IO		
Heater voltage		6.3	Pin	Electrode	
Heater current (A)		0.3	1	No connection	
Max. anode voltage		300	2	Heater	
Anode current (mA)		1.1	3	Anode	
Mutual conductance (mA/V)		1.2	4	Diode 2	
Amplification factor		70	5	Diode 1	
Anode impedance (ohms)		58,000	6	Pin omitted	
<u>CAPACITANCES (pF)</u>			7	Heater	
C _{ag}		1.7	8	Cathode	
C _{ge}		2.2	TC	Control grid	
C _{ae}		3.2	<u>TOP CAP</u>		
<u>NOTES</u> A. At V _a = 250V, V _{g1} = -3V.			See K1001/AI/D5.2		
			<u>DIMENSIONS</u>		
			See K1001/AI/D1		
			<u>Dimension</u>		<u>Min.</u>
A	mm	105	114		
B	mm	-	4.0		

TESTS

To be performed in addition to those applicable in K1001

	Test conditions			Test	Limits		No. tested
					Min	Max	
a	Vh	Va	Vg	Ih (A)	0.27	0.33	100% or S
	6.3	0	0				
b	<u>Triode Section</u>			Ia (mA)	0.7	2.0	100%
	6.3	250	-3				
c	6.3	250	-3	gm (mA/V)	0.8	1.5	100%
d	6.3	250	-3	Rev Ig (uA)	-	1.0	100%
e	<u>Diode Section</u>			Id (mA) (Note 1)	0.8	-	100%
	Vh	Vd					
	6.3	+10					

NOTES

1. This test to be applied to both diodes.

Data given for information of equipment designers and not subject to acceptance testing.

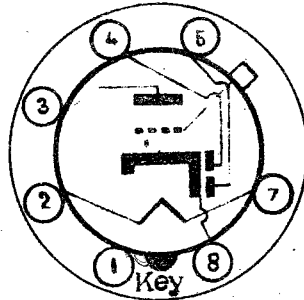
Issue No. b. Dated 18.12.44.

No. of pages :- 2.

Vh = 6.3 V.

Ih = 0.3 A.

See specification for dimensions, connections, main ratings and capacities.



Bottom View

OUTPUT VOLTAGE WITH 0.25 MEGOHM ANODE LOAD AT Va = 250, Vg = -3.

<u>A.C. Input Volts R.M.S.</u>		<u>A.C. Output Volts R.M.S.</u>
0.1	...	3.0
0.2	...	6.0
0.4	...	12.0
0.8	...	25.0

TYPICAL OPERATING CONDITIONS.

Anode voltage (V)	100	100	250
Grid voltage (V)	0	-1.5	-3.0
Anode current average (mA)	2.3	0.35	1.1
Amplification factor	60.0	70.0	70.0
Impedance (ohms)	43,000	87,500	58,000
Mutual Conductance (mA/V)	1.4	0.8	1.2
Cathode bias res. (ohms)			2,000
Optimum load res. (ohms)			250,000
Max. diode signal (V)			200
Max. diode current (mA)			0.8

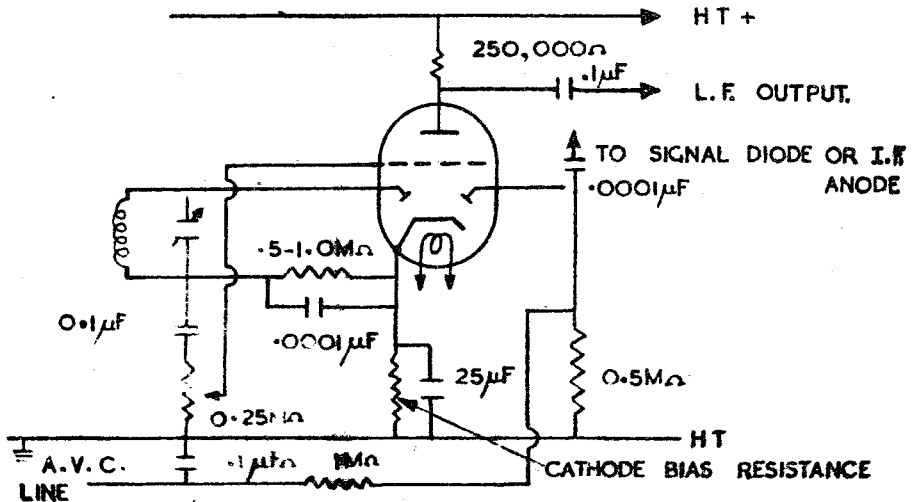
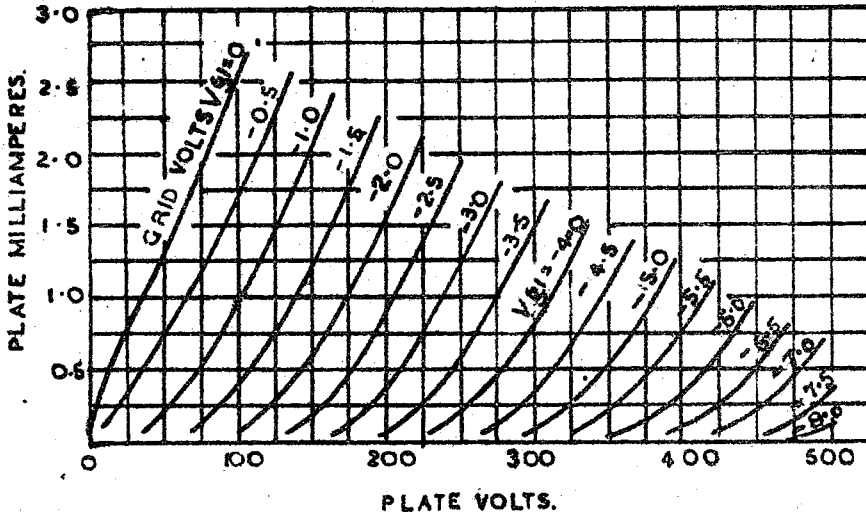
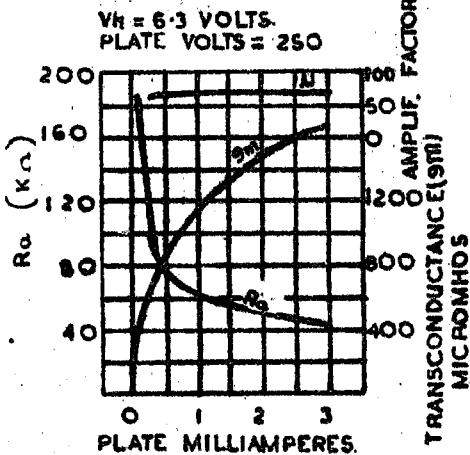


FIG. 1.

AVERAGE PLATE CHARACTERISTICS.
TRIODE UNIT



AVERAGE CHARACTERISTICS



VOLTS RMS

